

**AUDIO CELLULAR MATRIX**

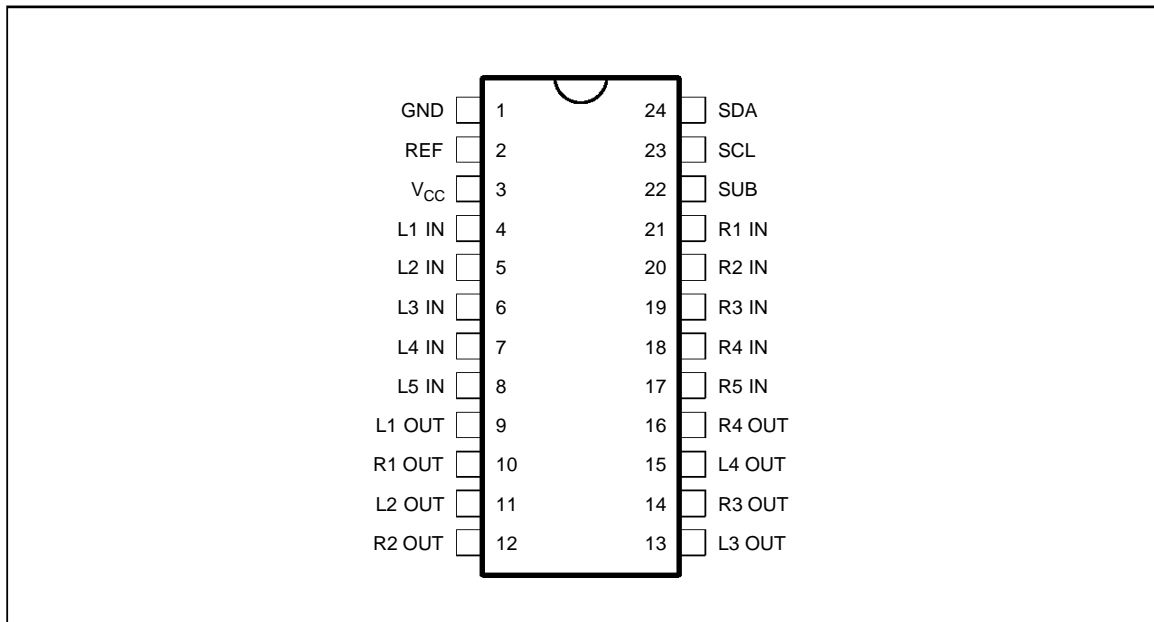
- 5 STEREO INPUTS - 4 STEREO OUTPUTS
- 3-STATE OPERATION FOR EACH OUTPUT
- GAIN OUTPUT CONTROL  
0dB/2/4/6dB/MUTE FOR EACH
- VERY LOW NOISE AND DISTORTION
- I<sup>2</sup>C BUS CONTROL
- 4 SUB-ADDRESS FACILITY
- 90dB CROSSTALK BETWEEN ANY INPUT AND OUTPUT



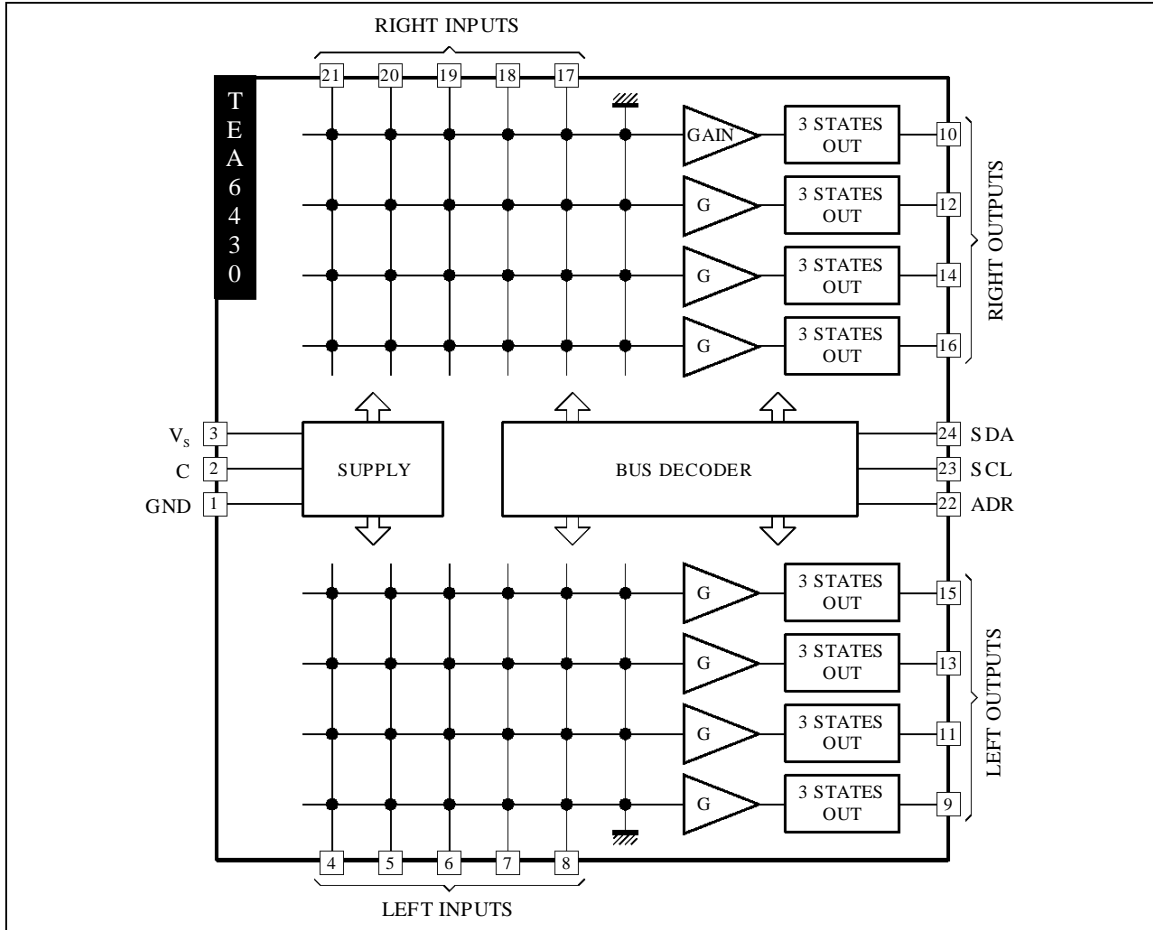
**DESCRIPTION**

The TEA6430 switches 5 stereo inputs on 4 stereo outputs, providing the customer with high quality sound (low noise, low distortion). The 4 stereo outputs can be set separately in high impedance state, to enable parallel connection of several devices (up to 4). All functions are controlled through the I<sup>2</sup>C bus.

**PIN CONNECTIONS**



**BLOCK DIAGRAM**



The output loads have to be larger than 2kΩ (typical 10kΩ) and 1500pF

**ABSOLUTE MAXIMUM RATINGS**

Symbol	Parameter	Value	Unit
V <sub>CC</sub>	Supply Voltage	12	V
V <sub>I</sub>	Voltage at Pin i to GND	0, V <sub>CC</sub>	V
T <sub>oper</sub>	Operating Ambient Temperature	0, + 70	°C
T <sub>stg</sub>	Storage Temperature	-20, + 150	°C

**THERMAL DATA**

Symbol	Parameter	Value	Unit
R <sub>th(j-a)</sub>	Junction-ambient Thermal Resistance	75	°C/W

**ELECTRICAL CHARACTERISTICS**

( $V_{CC} = 8V$ ,  $T_{amb} = 25^{\circ}C$ ,  $R_L = 10k\Omega$ ,  $R_G = 600\Omega$ ,  $f = 1kHz$ ,  $G = 0dB$ ,  $V_{IN} = 0.5V_{RMS}$  ;  
3-state is controlled by I<sup>2</sup>C bus, unless otherwise specified)

Symbol	Parameter	Test Conditions	Min.	Typ.	Max.	Unit
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**SUPPLY**

$V_{CC}$	Supply Voltage		7.2	8	10.2	V
$I_{CC}$	Supply Current		4	7	10	mA
RR	Ripple Rejection	$V_{IN} = 0.5V_{RMS}$ , $f = 1kHz$	70			dB

**AUDIO INPUTS**

$V_{IN}$	Max. Signal Amplitude		2			$V_{RMS}$
$V_{DC}$	Input DC Level			$V_{CC}/2$		V
$R_I$	Input Resistance		30	50	100	$k\Omega$

**AUDIO OUTPUTS**

$R_{OUT}$	Output Resistance			60	100	$\Omega$
$Z_{HI}$	Output "off" Impedance	$f = 20kHz$ , output disabled	50			$k\Omega$
$V_{OFF}$	DC Offset Change	Switching between inputs, see note 1		0.1	5	mV
$V_{OUT}$	Output DC Level		$0.4 V_{CC}$	$V_{CC}/2$	$0.6 V_{CC}$	V
$V_N$	Output Noise Voltage	$B = 20-20kHz$ , flat, see note 2		2.5		$\mu V$
$G$	Gain	$B = 20-20kHz$ , $R_L = 2k\Omega$	-0.5	0	+0.5	dB
	Isolation "off" State	$f = 1kHz$ , output disabled	85			dB
THD	Distortion	$V_{IN} = 1V_{RMS}$ , $f = 1kHz$		0.01	0.05	%
$V_{CL}$	Clipping Level	$d = 0.3\%$	2	2.3		$V_{RMS}$
$C_S$	L, R Channel Separation	$f = 1kHz$	-85			dB
	Crosstalk Audio Channels	$f = 1kHz$ , see note 3	-85	-100		dB
$C_L$	Load Capacitance		1500			pF

- Notes :
- DC offset change is less than maximum limit, in all configurations (one or several devices in parallel), provided that the reference Pins (P2) are all connected together.
  - Flat filter according to CCIR-468-4,  $B = 20Hz-20kHz$
  - Measured from any selected output which contains no signal to a set of other outputs.

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I<sup>2</sup>C BUS CHARACTERISTICS

Symbol	Parameter	Test Conditions	Standard Mode		Fast Mode		Unit
			Min.	Max.	Min.	Max.	

## SCL

V <sub>IL</sub>	Low Level Input Voltage		- 0.3	+ 1.5	- 0.3	+ 1.5	V
V <sub>IH</sub>	High Level Input Voltage		3.0	V <sub>CC</sub> + 0.5	3.0	V <sub>CC</sub> + 0.5	V
I <sub>LI</sub>	Input Leakage Current	V <sub>I</sub> = 0 to V <sub>DD</sub>	- 10	+ 10	- 10	+ 10	μA
f <sub>SCL</sub>	Clock Frequency		0	100	0	400	kHz
t <sub>R</sub>	Input Rise Time	1.5V to 3V		1000		300	ns
t <sub>F</sub>	Input Fall Time	1.5V to 3V		300		300	ns
C <sub>I</sub>	Input Capacitance			10		10	pF

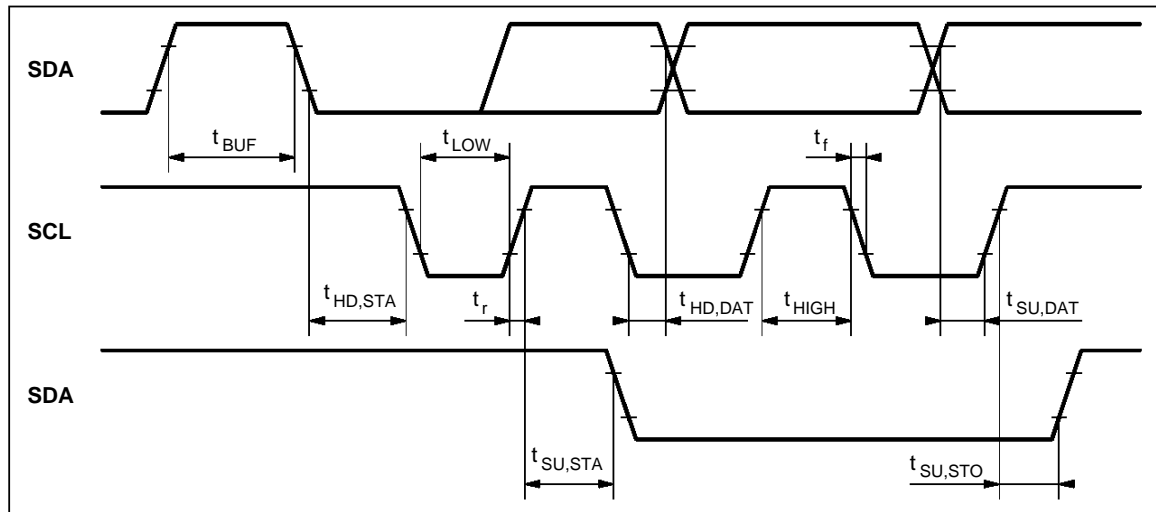
## SDA

V <sub>IL</sub>	Low Level Input Voltage		- 0.3	+ 1.5	- 0.3	+ 1.5	V
V <sub>IH</sub>	High Level Input Voltage		3.0	V <sub>CC</sub> + 0.5	3.0	V <sub>CC</sub> + 0.5	V
I <sub>LI</sub>	Input Leakage Current	V <sub>I</sub> = 0 to V <sub>DD</sub>	- 10	+ 10	- 10	+ 10	μA
C <sub>I</sub>	Input Capacitance			10		10	pF
t <sub>R</sub>	Input Rise Time	1.5V to 3V		1000		300	ns
t <sub>F</sub>	Input Fall Time	1.5V to 3V		300		300	ns
V <sub>OL</sub>	Low Level Output Voltage	I <sub>OL</sub> = 3mA		0.4		0.4	V
t <sub>F</sub>	Output Fall Time	3V to 1.5V		250		250	ns
C <sub>L</sub>	Load Capacitance			400		400	pF

## TIMING

t <sub>LOW</sub>	Clock Low Period		4.7		1.3		ms
t <sub>HIGH</sub>	Clock High Period		4.0		0.6		ms
t <sub>SU, DAT</sub>	Data Set-up Time		250		100		ns
t <sub>HD, DAT</sub>	Data Hold Time		0	340	0	340	ns
t <sub>SU, STO</sub>	Set-up Time from Clock High to Stop		4.0		0.6		μs
t <sub>BUF</sub>	Start Set-up Time following a Stop		4.7		1.3		μs
t <sub>HD, STA</sub>	Start Hold Time		4.0		0.6		μs
t <sub>SU, STA</sub>	Start Set-up Time following Clock Low-to High Transition		4.7		0.6		μs

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Figure 1 : I<sup>2</sup>C Bus Timing

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## I<sup>2</sup>C BUS SELECTION

### I<sup>2</sup>C Bus Slave Address

Address	A6	A5	A4	A3	A2	A1	A0	R/W
Value	1	0	0	1	1	A1	A0	0

### Sub-address I<sup>2</sup>C

Symbol	Parameter	Conditions	Pin 22 Voltage (typ.)	Unit
Vsub	Slave address HEXA	Sub-address (see note)		
1	98	A1 0 A0 0	GND	V
2	9E	1 1	V <sub>CC</sub>	V
3	9C	1 0	1/3	V <sub>CC</sub>
4	9A	0 1	2/3	V <sub>CC</sub>

**Note :** The first 3 levels are defined by connecting the sub-address pin to the appropriate level. Sub-address 4 will be selected when this pin is left open.

### Data Byte

	b7	b6	b5	b4	b3	b2	b1	b0	Action
	T	01	00	G1	G0	I2	I1	I0	
Input Select	*	*	*	*	*	0	0	0	IN1
	*	*	*	*	*	0	0	1	IN2
	*	*	*	*	*	0	1	0	IN3
	*	*	*	*	*	0	1	1	IN4
	*	*	*	*	*	1	0	0	IN5
	*	*	*	*	*	1	0	1	Mute
Output Select	*	0	0	*	*	*	*	*	OUT1
	*	0	1	*	*	*	*	*	OUT2
	*	1	0	*	*	*	*	*	OUT3
	*	1	1	*	*	*	*	*	OUT4
Gain	*	*	*	0	0	*	*	*	6dB
	*	*	*	0	1	*	*	*	4dB
	*	*	*	1	0	*	*	*	2dB
	*	*	*	1	1	*	*	*	0dB
Tri-state	0	*	*	*	*	*	*	*	Low impedance Tri-state
	1	*	*	*	*	*	*	*	

**Example :** 00111100 enables L(R)2 out and connect it with a gain of 0dB to L(R)5 in.

### Power On Reset

When active : outputs in 3-state. All outputs are disabled and L(R)5 is selected to drive all outputs. Gain = 0dB.

Symbol	Parameter	Conditions	Min.	Typ.	Max.	Unit
Reset	Start of Reset	Incr. V <sub>CC</sub>			2.5	V
		Decr. V <sub>CC</sub>			4.2	V
	End of Reset	Incr. V <sub>CC</sub>	4.5			V

TYPICAL PERFORMANCES

Figure 1 : Supply Current as a Function of Supply Voltage

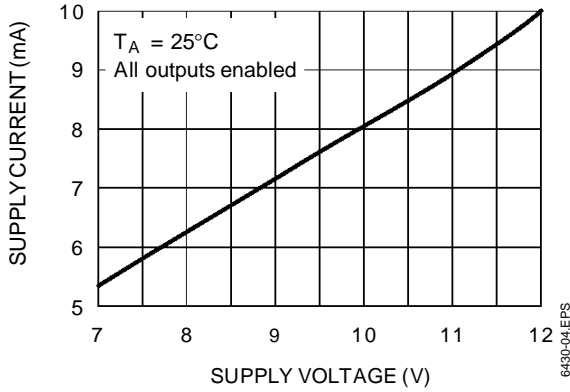


Figure 2 : Supply Current as a Function of Temperature

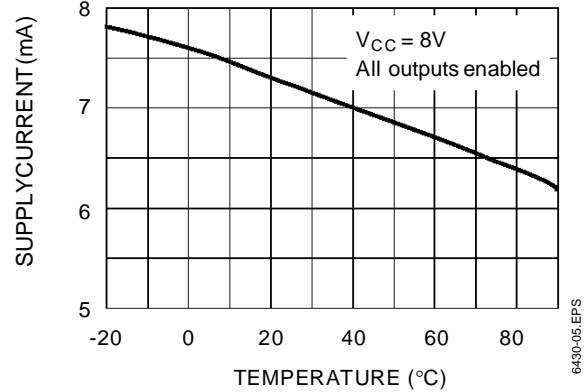


Figure 3 : Ripple Rejection as a Function of Supply Voltage

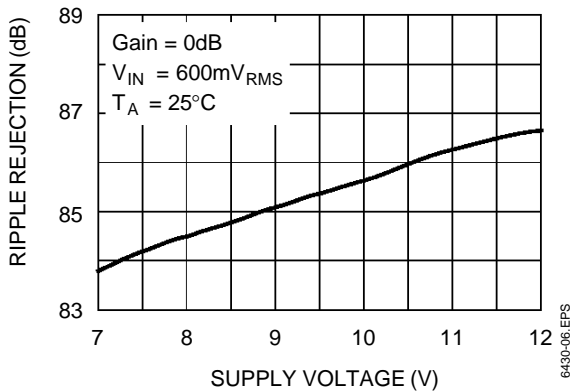


Figure 4 : Ripple Rejection as a Function of Temperature

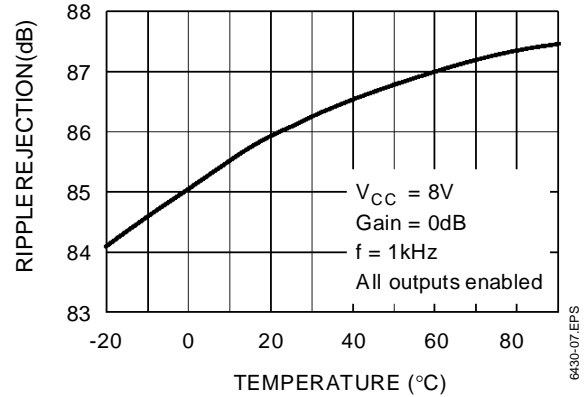


Figure 5 : Ripple Rejection as a Function of Gain

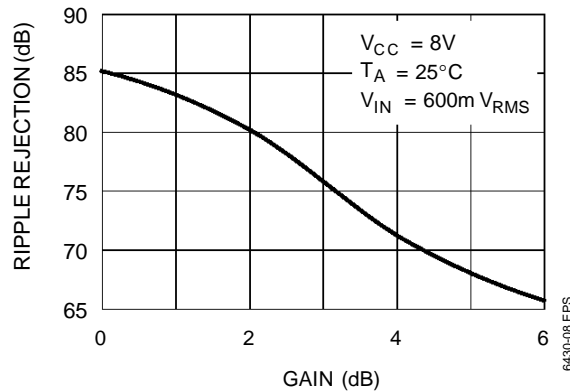
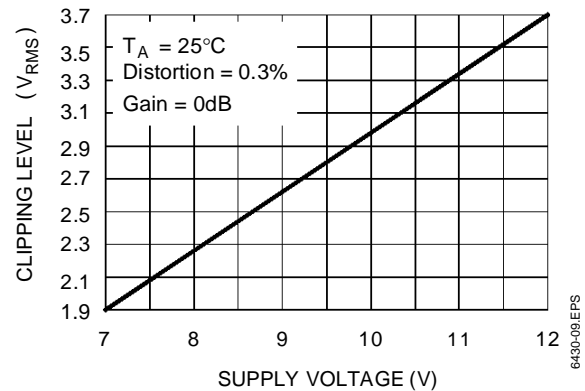
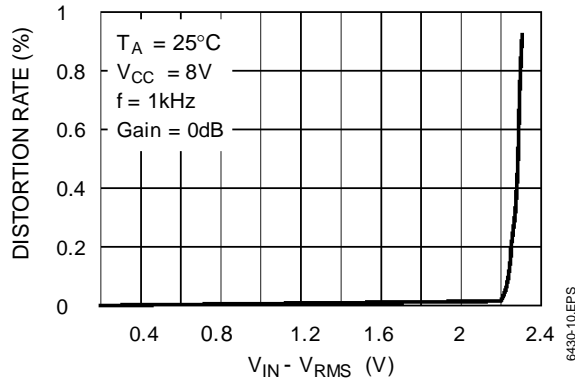
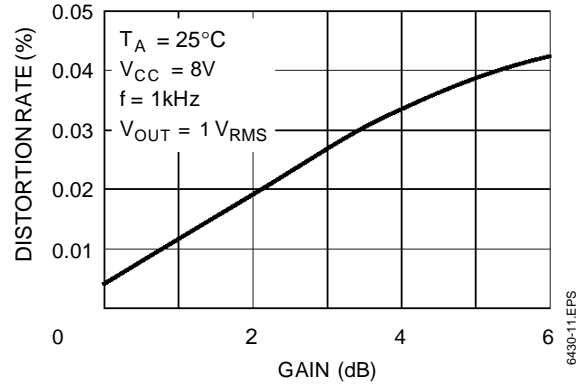
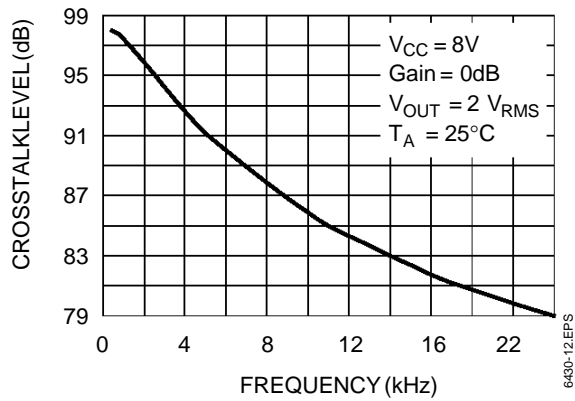
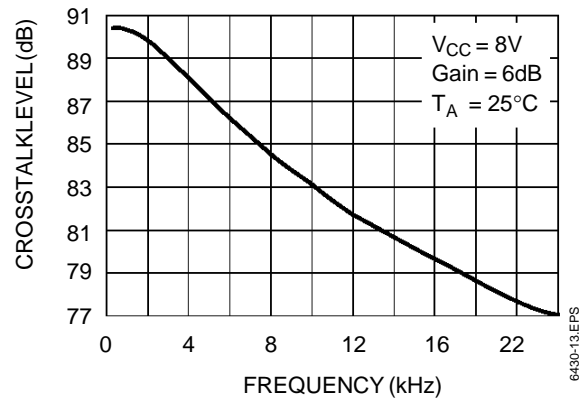


Figure 6 : Clipping Level as a Function of Supply Voltage

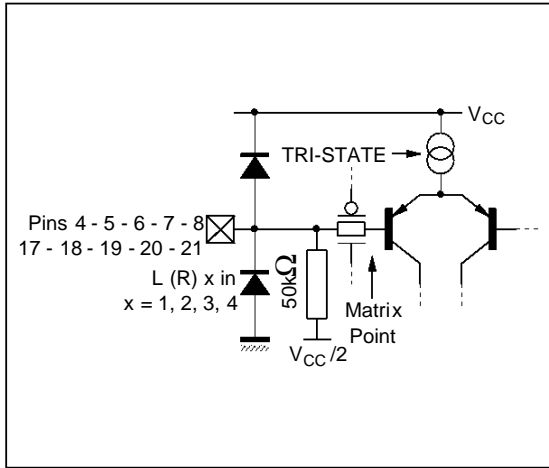


## TYPICAL PERFORMANCES (continued)

**Figure 7 :** Distortion as a Function of Input Level**Figure 8 :** Distortion as a Function of Gain**Figure 9 :** Crosstalk Level as a Function of Frequency (Gain = 0dB)**Figure 10 :** Crosstalk Level as a Function of Frequency (Gain = 6dB)

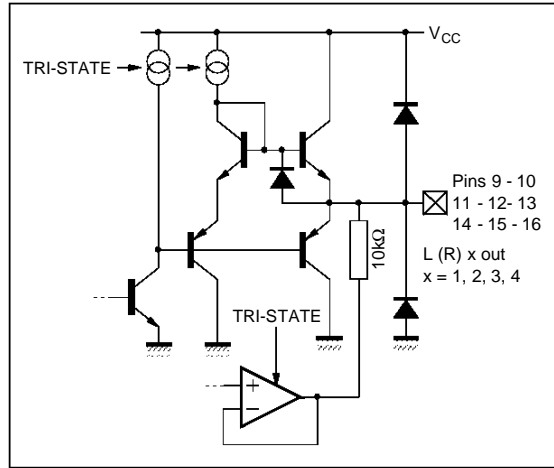
**PIN CONFIGURATIONS**

**Figure 11 : Audio IN**



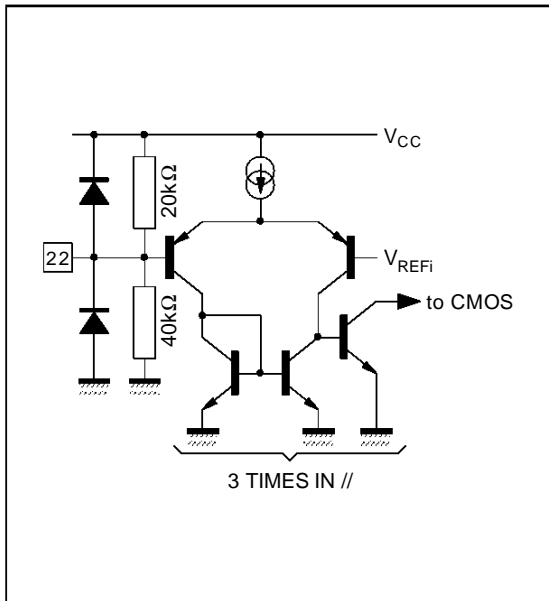
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**Figure 12 : Audio OUT**



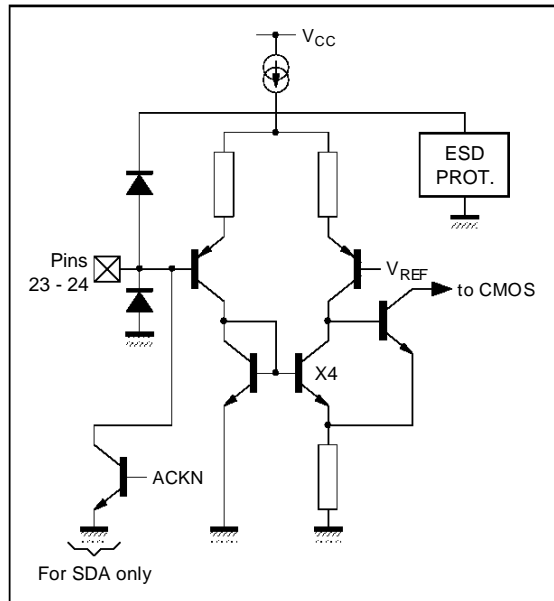
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**Figure 13 : PROG**



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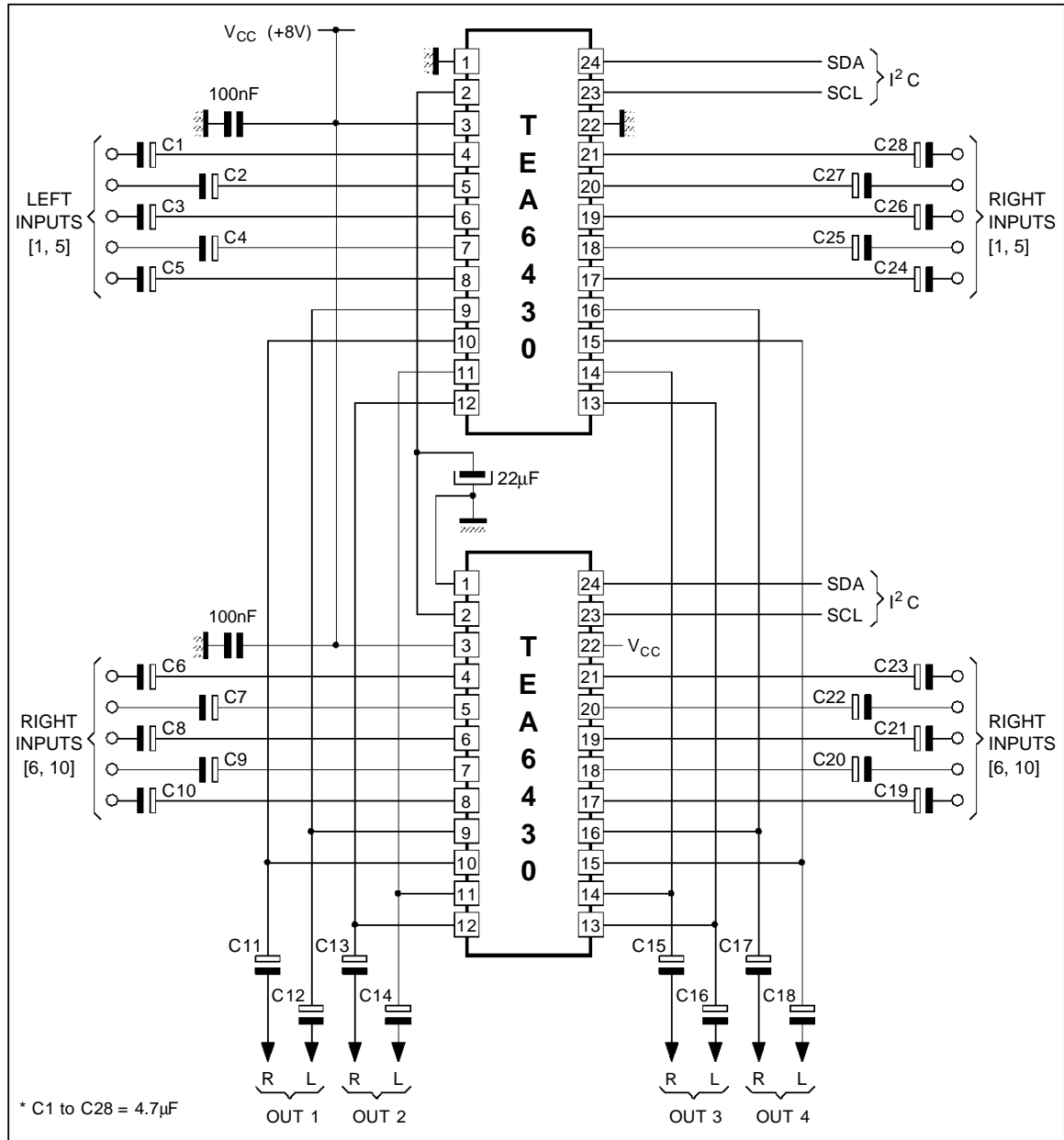
**Figure 14 : Bus Inputs**



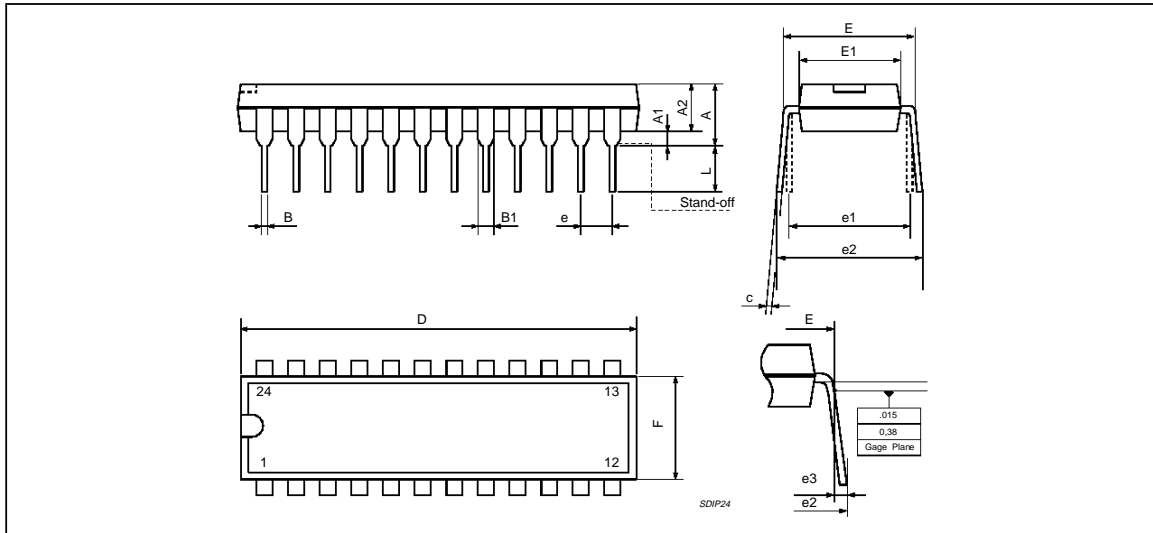
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## TYPICAL APPLICATION



**PACKAGE MECHANICAL DATA**  
24 PINS - PLASTIC SHRINK DIP



PMSDIP24.EPS

Dimensions	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A			5.08			0.20
A1	0.51			0.020		
A2	3.05	3.30	4.57	0.120	0.130	0.180
B	0.36	0.46	0.56	0.0142	0.0181	0.0220
B1	0.76	1.02	1.14	0.030	0.040	0.045
C	0.23	0.25	0.38	0.0090	0.0098	0.0150
D	22.61	22.86	23.11	0.890	0.90	0.910
E	7.62		8.64	0.30		0.340
E1	6.10	6.40	6.86	0.240	0.252	0.270
e		1.778			0.070	
e1		7.62			0.30	
e2			10.92			0.430
e3			1.52			0.060
L	2.54	3.30	3.81	0.10	0.130	0.150

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